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A hybrid piezoelectric and triboelectric nanogenerator with lead-free BZT-BCT/PDMS Composite and PVA film for scavenging mechanical energy

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Figure SI1: XRD Analysis of Sintered BZT-BCT Ceramic Pellet.



Figure SI2: Schematic diagram of PVA /PDMS/BZT-BCT H/P-TENG construction.



Figure SI3: (a) FESEM micrograph of BZT-BCT particles; (b) histogram showing the particle size distribution; (c) FESEM image of sintered ceramic pellets with homogeneous grain growth.



Figure SI4: XRD Analysis of BZT-BCT Polymer Composite Films with Varying wt.% of BZT-BCT inclusion.



Figure SI5: Dielectric spectra of BZT-BCT ceramic pellet.



Figure SI6: P-E Hysteresis Loop of BZT-BCT Ceramic Pellet.



Figure SI7: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with pure PDMS film.



Figure SI8: V_{oc} , J_{sc} and Q_{sc} output of H/P-TENG constructed with 15 wt.% PDMS/BZT-BCT composite films of various thickness.



Figure SI9: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with 5 wt.% PDMS/BZT-BCT polymer composite film under non-poled, forward-poled, and reverse-poled conditions.



Figure SI 10: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with 10 wt.% PDMS/BZT-BCT polymer composite film under non-poled, forward-poled, and reverse-poled conditions.



Figure SI 11: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with 20 wt.% PDMS/BZT-BCT polymer composite film under non-poled, forward-poled, and reverse-poled conditions.



Figure SI 12: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with 25 wt.% PDMS/BZT-BCT polymer composite film under non-poled, forward-poled, and reverse-poled conditions.



Figure SI2: Open-circuit voltage (V_{oc}), short-circuit current density (J_{sc}), short-circuit charge density (Q_{sc}) of H/P-TENG constructed with 30 wt.% PDMS/BZT-BCT polymer composite film under non-poled, forward-poled, and reverse-poled conditions.



Figure SI3: Power density output of H/P-TENG constructed with pure PDMS film with increasing load resistances.



Figure SI4: Power density output of H/P-TENG constructed with 5 wt.% polymer composite film with increasing load resistances under non-poled, forward-poled, and reverse-poled conditions.



Figure SI5: Power density output of H/P-TENG constructed with 10 wt.% polymer composite film with increasing load resistances under non-poled, forward-poled, and reverse-poled conditions.



Figure SI6: Power density output of H/P-TENG constructed with 20 wt.% polymer composite film with increasing load resistances under non-poled, forward-poled, and reverse-poled conditions.



Figure SI7: Power density output of H/P-TENG constructed with 25 wt.% polymer composite film with increasing load resistances under non-poled, forward-poled, and reverse-poled conditions.



Figure SI19: Power density output of H/P-TENG constructed with 30 wt.% polymer composite film with increasing load resistances under non-poled, forward-poled, and reverse-poled conditions.